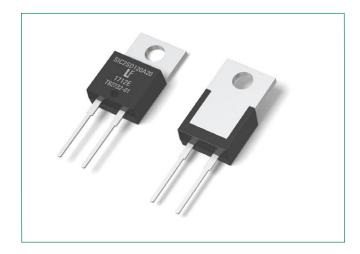
# **GEN2 SiC Schottky Diode** LSIC2SD120A20, 1200 V, 20 A, TO-220-2L

# LSIC2SD120A20









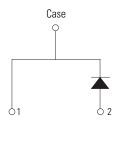
### **Description**

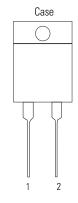
This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

#### **Features**

- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- · Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

#### Circuit Diagram TO-220-2L





## **Applications**

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- Industrial motor drives
- EV charging stations

#### **Environmental**

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo = HF Halogen Free
- Littelfuse "PB-free" logo = Pb-free lead plating

## **Maximum Ratings**

Characteristics	Symbol	Conditions	Value	Unit	
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	-	1200	V	
DC Blocking Voltage	V <sub>R</sub>	T <sub>J</sub> = 25 °C	1200	V	
		T <sub>C</sub> = 25 °C	54.5		
Continuous Forward Current	I <sub>F</sub>	T <sub>c</sub> = 135 °C	26.0	А	
		T <sub>c</sub> = 150 °C	20.0		
Non-Repetitive Forward Surge Current	I <sub>FSM</sub>	$T_C = 25  ^{\circ}\text{C}, T_P = 10  \text{ms},  \text{Half sine pulse}$	140	А	
Power Dissipation	D	T <sub>C</sub> = 25 °C	250	W	
Power Dissipation	P <sub>Tot</sub>	T <sub>c</sub> = 110 °C	108		
Operating Junction Temperature	T <sub>J</sub>	-	-55 to 175	°C	
Storage Temperature	T <sub>STG</sub>	-	-55 to 150	°C	
Soldering Temperature	T <sub>sold</sub>	-	260	°C	

# GEN2 SiC Schottky Diode LSIC2SD120A20, 1200 V, 20 A, T0-220-2L

#### **Electrical Characteristics**

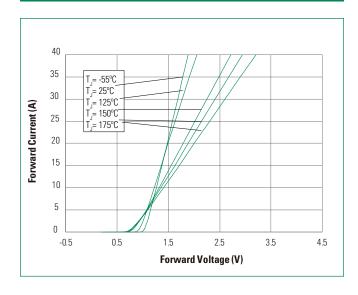
Characteristics	Symbol	Conditions	Value			Unit
		Conditions	Min.	Тур.	Max.	Unit
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 20 A, T <sub>J</sub> = 25 °C	-	1.5	1.8	V
		I <sub>F</sub> = 20 A, T <sub>J</sub> = 175 °C	-	2.2	-	
Reverse Current	I <sub>R</sub>	$V_{R} = 1200  V$ , $T_{J} = 25  ^{\circ}C$	-	<1	100	μА
		V <sub>R</sub> = 1200 V , T <sub>J</sub> = 175 °C	-	15		
Total Capacitance	С	$V_R = 1 V$ , $f = 1 MHz$	-	1142	-	pF
		$V_R = 400 \text{ V, f} = 1 \text{ MHz}$	-	108	-	
		V <sub>R</sub> = 800 V, f = 1 MHz	-	82	-	
Total Capacitive Charge	O <sub>c</sub>	$V_{R} = 800 \text{ V, } Q_{c} = \int_{0}^{V_{R}} C(V)dV$	-	115	-	nC

Footnote: T<sub>J</sub> = +25 °C unless otherwise specified

# **Thermal Characteristics**

Characteristics	Symbol	Conditions		Value		Unit
		Conditions	Min.	Тур.	Max.	Oiiit
Thermal Resistance	R <sub>euc</sub>	-	-	0.6	-	°C/W

# **Figure 1: Typical Foward Characteristics**



# **Figure 2: Typical Reverse Characteristics**

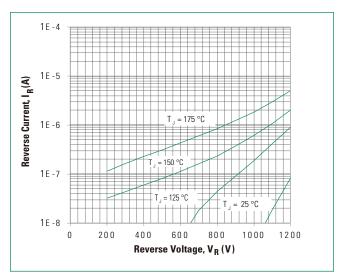




Figure 3: Power Derating

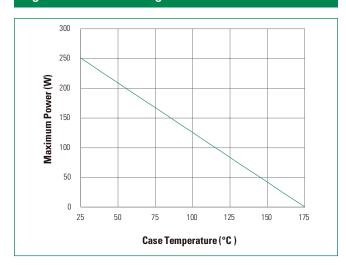


Figure 4: Current Derating

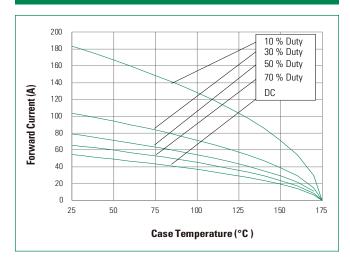


Figure 5: Capacitance vs. Reverse Voltage

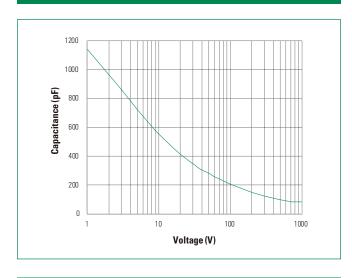


Figure 6: Capacitive Charge vs. Reverse Voltage

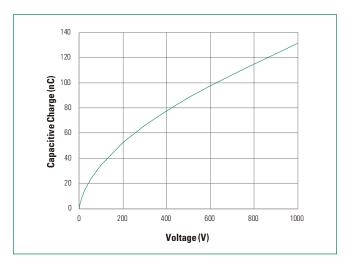


Figure 7: Stored Energy vs. Reverse Voltage

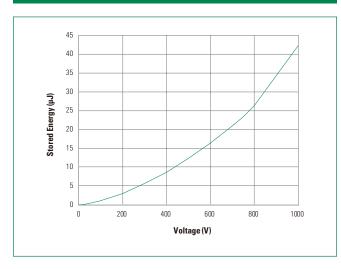
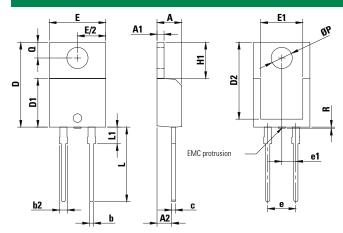


Figure 8: Transient Thermal Impedance

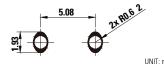


# **GEN2 SiC Schottky Diode** LSIC2SD120A20, 1200 V, 20 A, TO-220-2L

# Dimensions-Package TO-220-2L

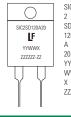


Recommended Solder Pad Layout



	Millimeters			
Symbol	Min	Nom	Max	
Α	4.32	4.45	4.70	
A1	1.14	1.27	1.40	
A2	2.20	-	2.74	
b	0.69	-	0.90	
b2	1.17	-	1.62	
С	0.36	-	0.60	
D	14.90	-	15.90	
D1	8.62	-	9.40	
D2	12.50	-	12.95	
E	9.70	10.18	10.36	
E1	7.57	7.61	8.30	
e1	-	2.54	-	
е	5.03	5.08	5.13	
H1	6.30	6.55	6.80	
L	12.88	13.50	14.00	
L1	2.39	-	3.25	
øΡ	3.50	3.84	3.96	
Q	2.65	-	3.05	
R	-	-	0.25	

## Part Numbering and Marking System



- = Gen2 SD 120
  - = Schottky Diode = Voltage Rating (1200 V)
    - = TO-220 Package (2 Lead) = Current Rating (20 A) = Year
- ww = Week = Trace Code (any letter)

ZZZZZZ-ZZ = Lot Number

## **Packing Options**

Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD120A20	SIC2SD120A20	Tube (50pcs)	1000

# Packing Specification (Tube for TO-220-2L)

- NOTES:

  1. Material transparent extruded PVC with antistatic dipping

  2. Radius: 0.5 maximum unless otherwisen specified

  3. Critical areas: Labelled in Box

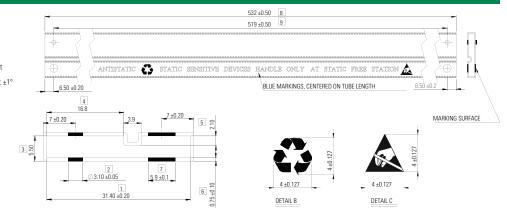
  4. All pin plug holes are considered critical dimension

  5. Marking Font Type: Times new roman, 3.12 ±0.127 in height

  6. Material Thickness: 0.75 ±0.10

  7. Tolerance unless otherwise specified: Decimal: ±0.05 Angle: ±1°

  8. Unit: Millimeter (mm)



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